

Q

High Speed CMOS 32-Bit Register in Millipaq™

QS74FCT4X374ATQ3
QS74FCT4X374CTQ3
QS74FCT4X2374ATQ3

FEATURES/BENEFITS

- 32-bit Function compatible to the 74F374, 74ABT374, 74FCT374T and 74FCT2374T
- QS74FCT4X374T: $I_{OL} = 48 \text{ mA}$
- QS74FCT4X2374T: $I_{OL} = 12 \text{ mA}$
- Low CMOS power consumption
- Ground bounce controlled outputs
- A and C speed grades; 5.2 ns t_{PD} for C
- Smallest footprint 32-bit logic solution
- 80-pin, 150-mil Millipaq package (Q3)
- Easy layout flow-through pinout
- Tube or tape-and-reel shipment
- TTL-compatible input and output levels
- Undershoot clamp diodes on all inputs

DESCRIPTION

The FCT4X374T and FCT4X2374T are 32-bit registers with three-state outputs that are useful for bus-oriented applications. Output Enable ($\overline{OE}$) inputs enable the selected port for output. All inputs have clamp diodes for undershoot noise suppression. All outputs have ground bounce suppression (see QSI Application Note AN-01), and outputs will not load an active bus when V_{CC} is removed from the device. The Millipaq 80-pin small outline package provides the smallest possible footprint while also offering an easy to layout flow-through, dual-in-line format.

Figure 1. Functional Block Diagram

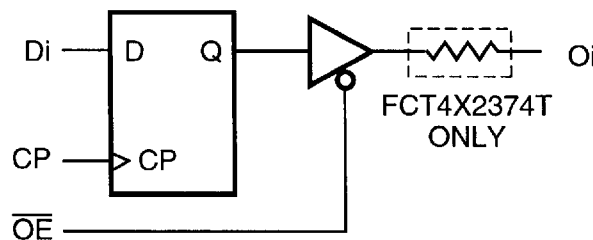


Figure 2. Pin Configuration
(All pins top view)

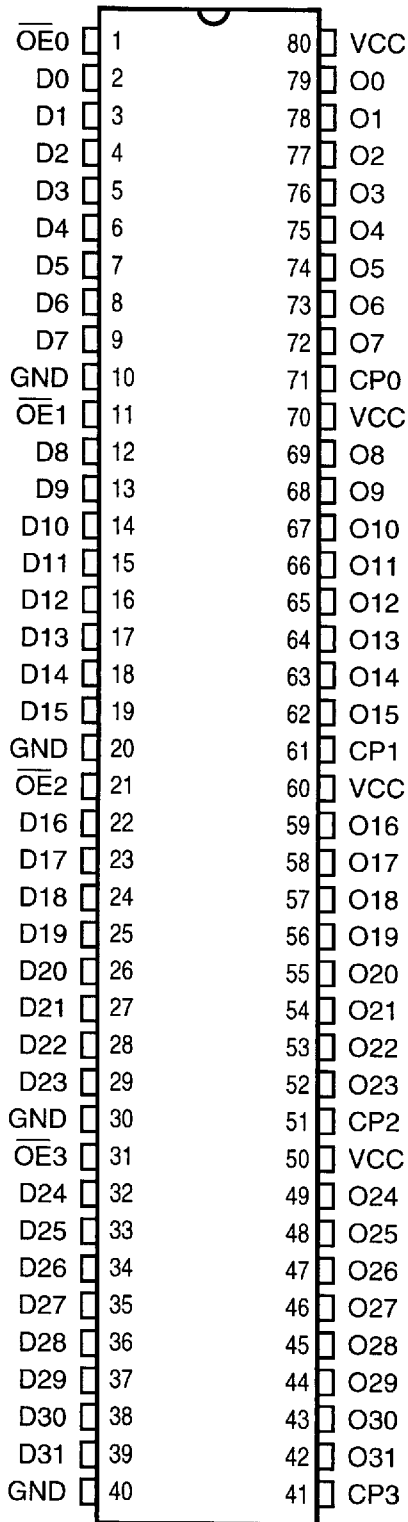


Table 1. Pin Description

Name	I/O	Description
Di	I	Data Inputs
Oi	O	Data Outputs
CPi	I	Clock Inputs
$\overline{OE}0$	I	Output Enable, O7-O0
$\overline{OE}1$	I	Output Enable, O15-O8
$\overline{OE}2$	I	Output Enable, O23-O16
$\overline{OE}3$	I	Output Enable, O31-O24

Table 2. Function Table

$\overline{OE}n$	CPn	Di	Internal Q Value	Outputs	Function
H	X	X	X	Hi-Z	Disable Outputs
L	$\uparrow$	L	L	L	Load Input Data,
L	$\uparrow$	H	H	H	Enable Outputs
H	$\uparrow$	L	L	Hi-Z	Load Input Data,
H	$\uparrow$	H	H	Hi-Z	Disable Outputs

Table 3. Absolute Maximum Ratings

Supply Voltage to Ground	-0.5V to +7.0V
DC Output Voltage V_{OUT}	-0.5V to +7.0V
DC Input Voltage V_{IN}	-0.5V to +7.0V
AC Input Voltage (for a pulse width ≤ 20 ns)	-3.0V
DC Input Diode Current with $V_{IN} < 0$	-20 mA
DC Output Diode Current with $V_{OUT} < 0$	-50 mA
DC Output Current Max. Sink Current/Pin	120 mA
Maximum Power Dissipation	1.4 watts (0 LFPM)
T_{STG} Storage Temperature	-65° to +150°C

Note: Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to this device resulting in functional or reliability type failures.

Table 4. Capacitance

$T_A = 25^\circ\text{C}$, $f = 1$ MHz, $V_{IN} = 0\text{V}$, $V_{OUT} = 0\text{V}$

Pins	Typ	Unit
1-9, 11-19, 21-29, 31-39, 41, 51, 61, 71	4	pF
42-49, 52-59, 62-69, 72-79	6	pF

Note: Capacitance is characterized but not production tested.

Table 5. DC Electrical Characteristics Over Operating Range

Commercial $T_A = 0^\circ\text{C}$ to 70°C , $V_{CC} = 5.0\text{V} \pm 5\%$

Symbol	Parameter	Test Conditions	Min	Typ ⁽¹⁾	Max	Unit
V_{IH}	Input HIGH Voltage	Logic HIGH for All Inputs	2.0	—	—	V
V_{IL}	Input LOW Voltage	Logic LOW for All Inputs	—	—	0.8	V
ΔV_T	Input Hysteresis	$V_{TLH} - V_{THL}$ for All Inputs ⁽³⁾	—	0.2	—	V
I_{IH} I_{IL}	Input Current Input HIGH or LOW	$V_{CC} = \text{Max.}, 0 \leq V_{IN} < V_{CC}$	—	—	5	μA
I_{OZ}	Off-State Output Current (Hi-Z)	$V_{CC} = \text{Max.}, 0 \leq V_{IN} \leq V_{CC}$	—	—	5	μA
I_{OS}	Short Circuit Current QS74FCT4X374T	$V_{CC} = \text{Max.}, V_{OUT} = \text{GND}^{(2,3)}$	-60	—	—	mA
I_{OR}	Current Drive QS74FCT4X2374T (25 Ω)	$V_{CC} = \text{Max.}, V_{OUT} = 2.0\text{V}$	50	—	—	mA
V_{IC}	Input Clamp Voltage	$V_{CC} = \text{Min.}, I_{IN} = -18 \text{ mA}^{(3)}$	—	-0.7	-1.2	V
V_{OH}	Output HIGH Voltage	$V_{CC} = \text{Min.}, I_{OH} = -15 \text{ mA}$	2.4	—	—	V
V_{OL}	Output LOW Voltage QS74FCT4X374T	$V_{CC} = \text{Min.}, I_{OL} = 48 \text{ mA}$	—	—	0.50	V
V_{OL}	Output LOW Voltage QS74FCT4X2374T (25 Ω)	$V_{CC} = \text{Min.}, I_{OL} = 12 \text{ mA}$	—	—	0.50	V
R_{OUT}	Output Resistance QS74FCT4X2374T (25 Ω)	$V_{CC} = \text{Min.}, I_{OL} = 12 \text{ mA}$	20	28	40	Ω

Notes:

1. Typical values indicate $V_{CC} = 5.0\text{V}$ and $T_A = 25^\circ\text{C}$.
2. Not more than one output should be shorted and the duration is ≤ 1 second.
3. These parameters are guaranteed by design but not production tested.

Table 6. Power Supply Characteristics

Symbol	Parameter	Test Conditions ⁽¹⁾	Typ	Max	Unit
I _{cc}	Quiescent Power Supply Current	V _{CC} = Max., Freq = 0 0V ≤ V _{IN} ≤ 0.2V or V _{CC} -0.2V ≤ V _{IN} ≤ V _{CC}	—	6.0	mA
ΔI _{cc}	Supply Current per Input @ TTL HIGH	V _{CC} = Max., V _{IN} = 3.4V, Freq = 0 ⁽²⁾	—	2.0	mA
Q _{CCD}	Supply Current per Output per MHz	V _{CC} = Max., Outputs Open and Enabled One Bit Toggling @ 50% Duty Cycle Other Inputs at GND or V _{CC} ^(3,4)	90	—	μA/ MHz

Notes:

- For conditions shown as Min. or Max., use the appropriate values specified under DC specifications.
- Per TTL driven input (V_{IN} = 3.4V).
- For flip-flops, Q_{CCD} is measured by switching one of the data input pins so that the output changes every clock cycle. This is a measurement of device power consumption only and does not include power to drive load capacitance or tester capacitance. This parameter is guaranteed by design but not production tested.
- Total power supply current (I_c) can be computed using the above parameters as explained in *FCT-T Family Characteristics*.

Table 7. Switching Characteristics Over Operating Range

Commercial T_A = 0°C to 70°C, V_{CC} = 5.0V ± 5%

C_{LOAD} = 50 pF, R_{LOAD} = 500Ω unless otherwise noted.

Symbol	Description	4X374A/4X2374A		4X374C		Unit
		Min	Max	Min	Max	
t _{PHL} t _{PLH}	Propagation Delay ⁽¹⁾ CP to O _i	2.0	6.5	2.0	5.2	ns
t _{PZH} t _{PZL}	Output Enable Time ⁽¹⁾	1.5	6.5	1.5	5.5	ns
t _{PHZ} t _{PLZ}	Output Disable Time ⁽²⁾	1.5	5.5	1.5	5.0	ns
t _s	Data Setup Time	2.0	—	1.5	—	ns
t _H	Data Hold Time	1.5	—	1.0	—	ns
t _w	Clock Pulse Width ⁽²⁾ HIGH or LOW	5.0	—	4.0	—	ns
t _{sko}	Rising Edge Skew ⁽²⁾	—	1.0	—	1.0	ns

Notes:

- Minimums guaranteed but not production tested. See Test Circuit and Waveforms.
- This parameter is guaranteed but not production tested.